High Voltage, Current Shunt Monitor

Data Sheet **AD8211**

FEATURES

- Qualified for automotive applications
- ±4000 V human body model (HBM) electrostatic discharge (ESD)
- High common-mode input voltage range: −2 V to +65 V
- Continuous input voltage range: −3 V to +68 V
- Buffered output voltage
- Wide operating temperature range
  - 5-lead SOT: −40°C to +125°C
- Excellent ac and dc performance
  - 5 µV/°C typical offset drift
  - −13 ppm/°C typical gain vs. temperature
  - 120 dB typical common-mode rejection ratio (CMRR) at dc

APPLICATIONS

- High-side current sensing
  - Motor controls
  - Transmission controls
  - Engine management
  - Suspension controls
  - Vehicle dynamic controls
  - DC-to-dc converters

FUNCTIONAL BLOCK DIAGRAM

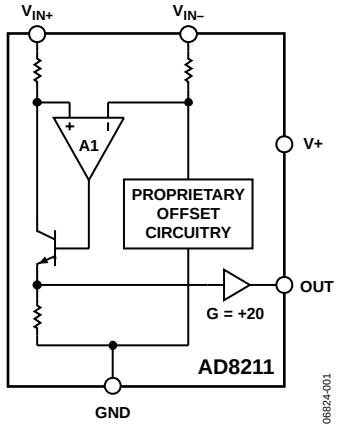


Figure 1.

GENERAL DESCRIPTION

The AD8211 is a high voltage, precision current shunt amplifier. It features a set gain of 20 V/V, with a typical ±0.35% gain error over the entire temperature range. The buffered output voltage directly interfaces with any typical converter. Excellent common-mode rejection from −2 V to +65 V is independent of the 5 V supply. The AD8211 performs unidirectional current measurements across a shunt resistor in a variety of industrial and automotive applications, such as motor control, solenoid control, or battery management.

Special circuitry is devoted to output linearity being maintained throughout the input differential voltage range of 0 mV to 250 mV, regardless of the common-mode voltage present. The AD8211 has an operating temperature range of −40°C to +125°C and is offered in a small 5-lead SOT package.

Rev. C
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REVISION HISTORY

12/2016—Rev. B to Rev. C

Changes to Figure 27 ...

11/2015—Rev. A to Rev. B

Changes to Figure 3 ... 5
Changes to Figure 25 to Figure 27 ... 12

3/2011—Rev. 0 to Rev. A

Added Automotive Products Information ... Throughout
Changes to General Description, Gain Error Percentage ... 1
Changes to Table 1 ... 3
Changes to Table 2 ... 4
Updated Outline Dimensions ... 13
Changes to Ordering Guide ... 13

7/2007—Revision 0: Initial Version

SPECIFICATIONS

T_{OPR} = −40°C to +125°C, T_A = 25°C, V_S = 5 V, R_L = 25 kΩ (R_L is the output load resistor), unless otherwise noted.

Table 1.

	Y Grade			W Grade				
Parameter	**Min**	**Typ**	**Max**	**Min**	**Typ**	**Max**	**Unit**	**Test Conditions/Comments**
GAIN								
Initial		20			20		V/V	
Accuracy			±0.25			±0.25	%	$V_O \geq 0.1$ V dc
Accuracy Over Temperature		±0.35				±0.4	%	T_{OPR}
Gain vs. Temperature		−13			−13		ppm/°C	T_{OPR}[1]
VOLTAGE OFFSET								
Offset Voltage, Referred to Input (RTI)			±1			±1	mV	25°C
Over Temperature (RTI)		±2.2				±2.5	mV	T_{OPR}
Offset Drift		5			5		µV/°C	T_{OPR}[2]
INPUT								
Input Impedance								
Differential		5			5		kΩ	
Common Mode		5			5		MΩ	Common-mode voltage > 5 V
		3.5			3.5		kΩ	Common-mode voltage < 5 V
Common-Mode Input Voltage Range	−2		+65	−2		+65	V	Common-mode continuous
Differential Input Voltage Range		250			250		mV	Differential input voltage
Common-Mode Rejection	100	120		100	120		dB	T_{OPR}, f = dc, V_{CM} > 5 V, see Figure 5
	80	90		80	90		dB	T_{OPR}, f = dc, V_{CM} < 5 V, see Figure 5
OUTPUT								
Output Voltage Range Low	0.1	0.05		0.1	0.05		V	T_{OPR}
Output Voltage Range High		4.95	4.9		4.95	4.9	V	T_{OPR}
Output Impedance		2			2		Ω	
DYNAMIC RESPONSE								
Small Signal −3 dB Bandwidth		500			500		kHz	
Slew Rate		4.5			4.5		V/µs	
NOISE								
0.1 Hz to 10 Hz, RTI		7			7		µV p-p	
Spectral Density, 1 kHz, RTI		70			70		nV/√Hz	
POWER SUPPLY								
Operating Range	4.5		5.5	4.5		5.5	V	
Quiescent Current over Temperature		1.2	2.0		1.2	2.0	mA	V_{CM} > 5 V[3], see Figure 12
Power Supply Rejection Ratio	76			76			dB	
TEMPERATURE RANGE								
For Specified Performance	−40		+125	−40		+125	°C	

[1] The mean of the gain drift distribution is typically −13 ppm/°C, with σ = 3 ppm/°C.
[2] The mean of the offset drift distribution is typically 5 µV/°C, with σ = 3 µV/°C.
[3] When the input common-mode voltage is less than 5 V, the supply current increases, which can be calculated by $I_S = -0.275 (V_{CM}) + 2.5$.

ABSOLUTE MAXIMUM RATINGS

Table 2.

Parameter	Rating
Supply Voltage	12.5 V
Continuous Input Voltage Range	−3 V to +68 V
Reverse Supply Voltage	−0.3 V
Differential Input Voltage	±500 mV
ESD Rating	
Human Body Model (HBM)	±4000 V
Charged Device Model (CDM)	±1000 V
Operating Temperature Range	−40°C to +125°C
Storage Temperature Range	−65°C to +150°C

Stresses at or above those listed under Absolute Maximum Ratings may cause permanent damage to the product. This is a stress rating only; functional operation of the product at these or any other conditions above those indicated in the operational section of this specification is not implied. Operation beyond the maximum operating conditions for extended periods may affect product reliability.

ESD CAUTION



ESD (electrostatic discharge) sensitive device. Charged devices and circuit boards can discharge without detection. Although this product features patented or proprietary protection circuitry, damage may occur on devices subjected to high energy ESD. Therefore, proper ESD precautions should be taken to avoid performance degradation or loss of functionality.

PIN CONFIGURATION AND FUNCTION DESCRIPTIONS

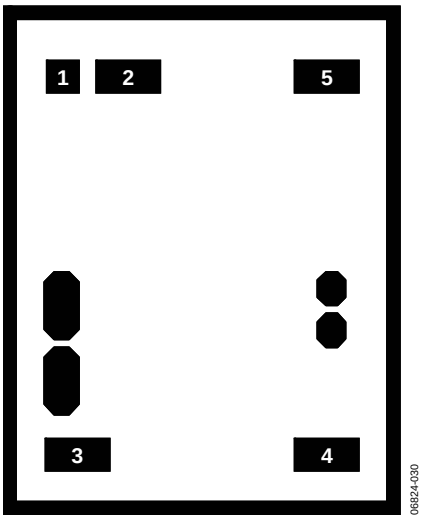


Figure 2. Metallization Diagram

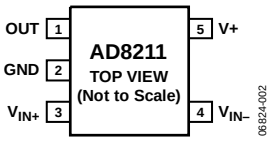


Figure 3. Pin Configuration

Table 3. Pin Function Descriptions

Pin No.	Mnemonic	X	Y	Description
1	OUT	−277	+466	Buffered Output
2	GND	−140	+466	Ground
3	V_{IN+}	−228	−519	Noninverting Input
4	V_{IN-}	+229	−519	Inverting Input
5	V+	+264	+466	Supply

TYPICAL PERFORMANCE CHARACTERISTICS

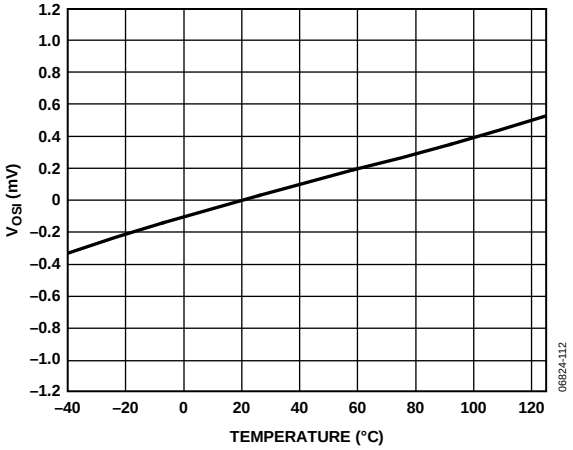


Figure 4. Typical Offset (V_{OSI}) vs. Temperature

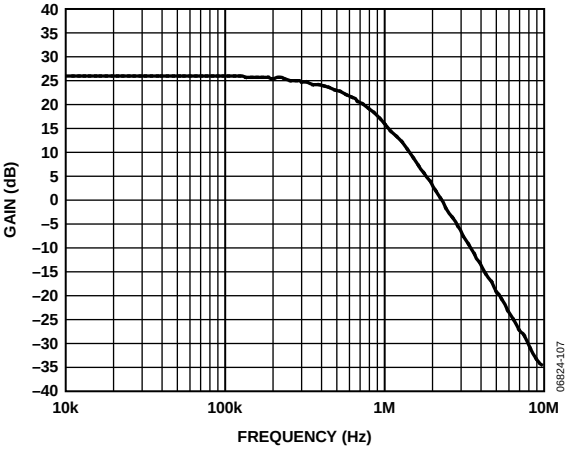


Figure 7. Typical Small Signal Bandwidth (V_{OUT} = 200 mV p-p)

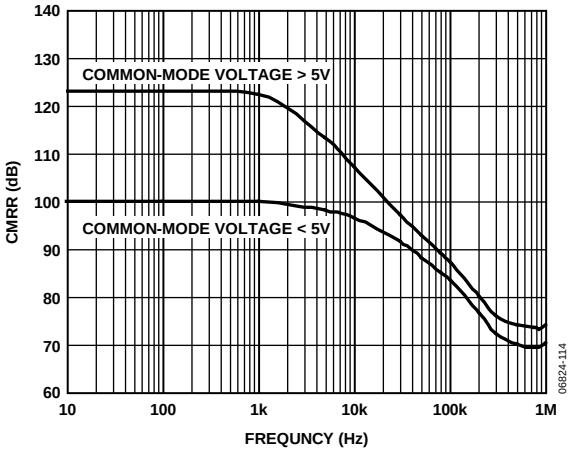


Figure 5. Typical CMRR vs. Frequency

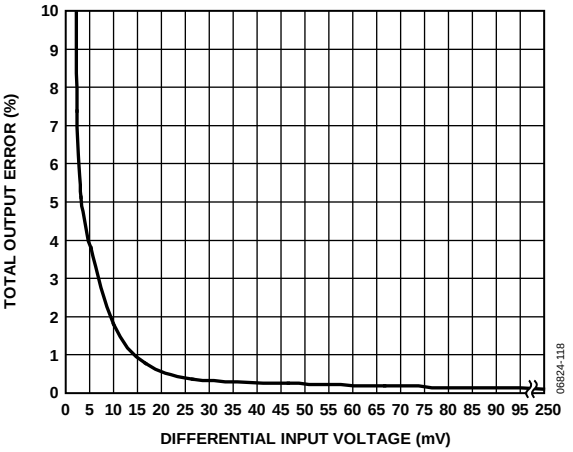


Figure 8. Total Output Error vs. Differential Input Voltage

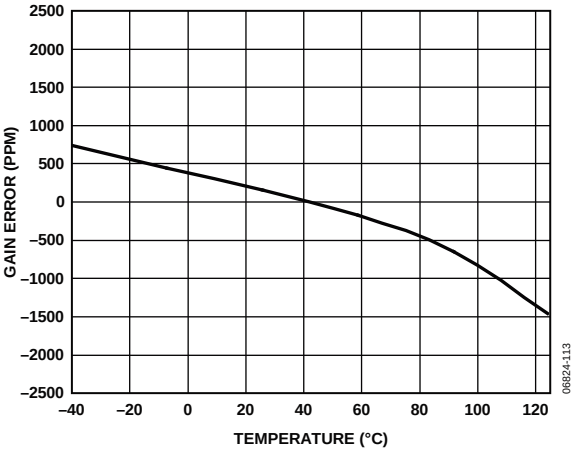


Figure 6. Typical Gain Error vs. Temperature

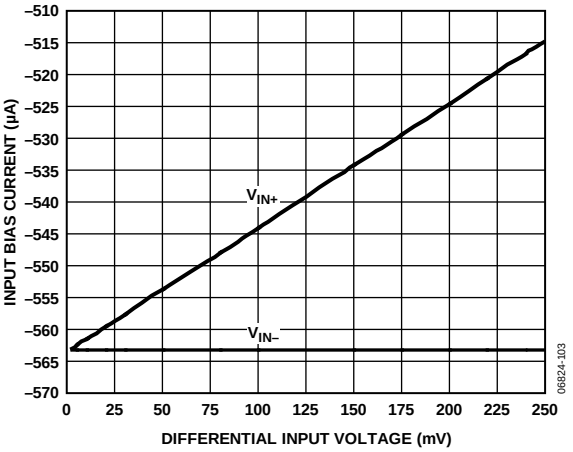


Figure 9. Input Bias Current vs. Differential Input Voltage, V_{CM} = 0 V

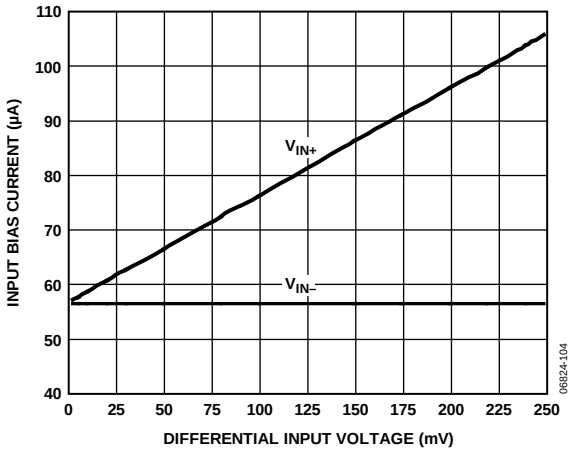


Figure 10. Input Bias Current vs. Differential Input Voltage, V_{CM} = 5 V

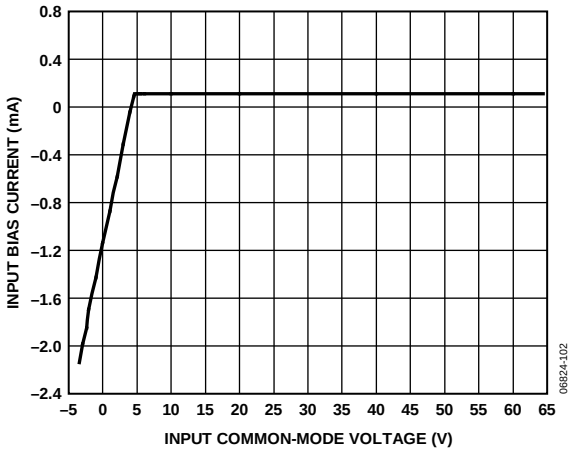


Figure 11. Input Bias Current vs. Input Common-Mode Voltage

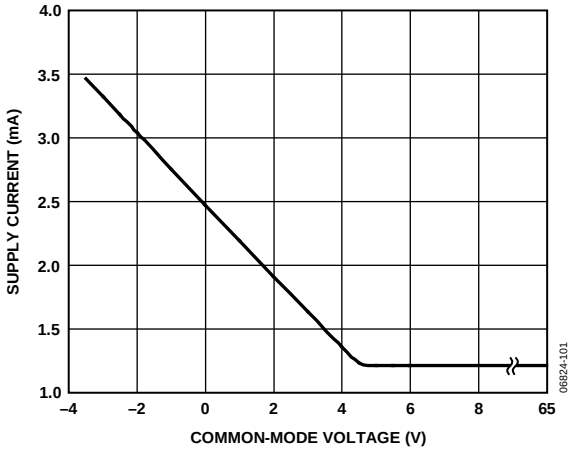


Figure 12. Supply Current vs. Common-Mode Voltage

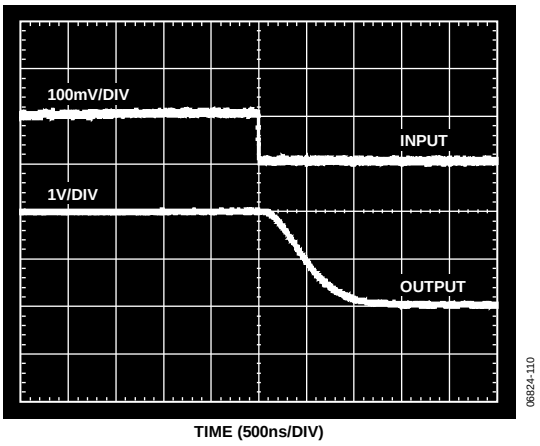


Figure 13. Fall Time

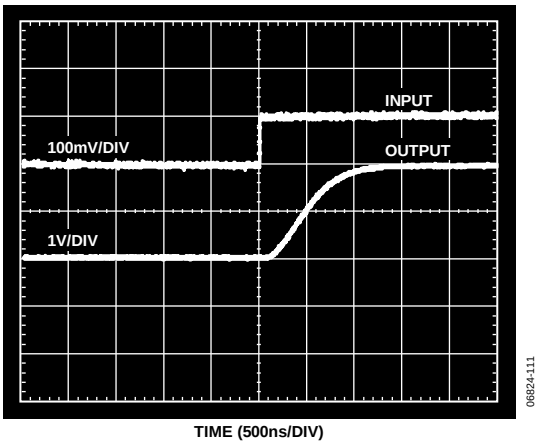


Figure 14. Rise Time

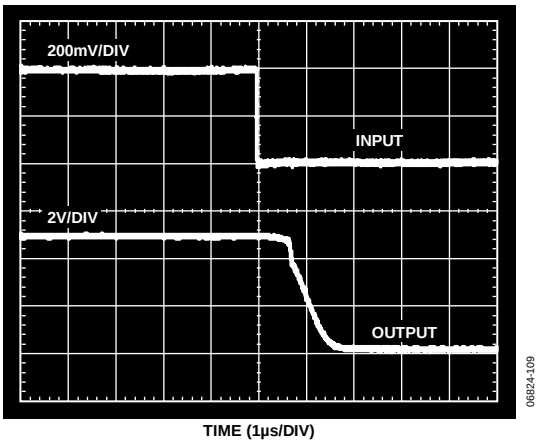


Figure 15. Differential Overload Recovery (Falling)

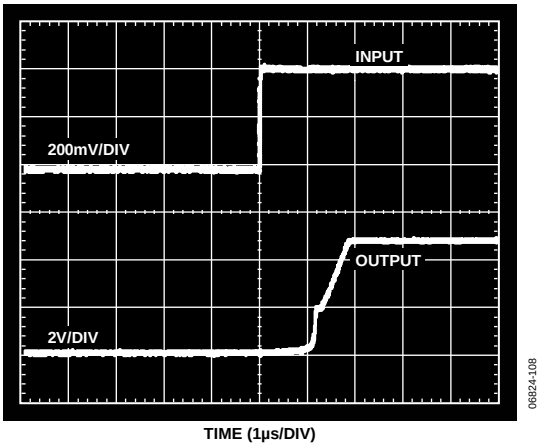


Figure 16. Differential Overload Recovery (Rising)

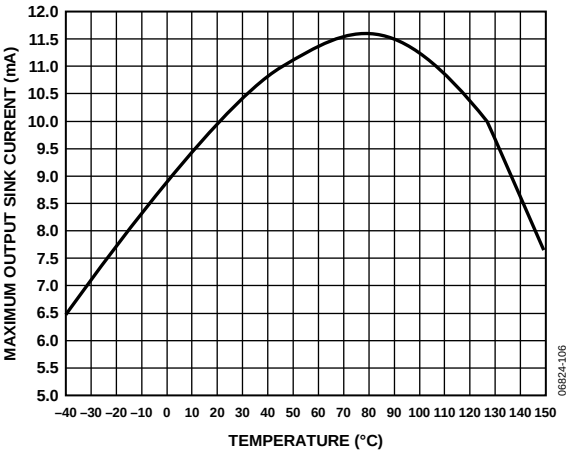


Figure 19. Maximum Output Sink Current vs. Temperature

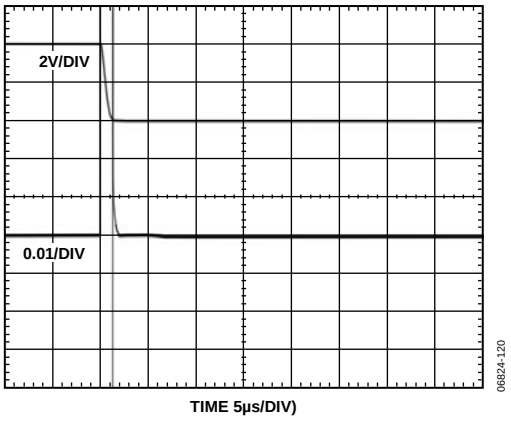


Figure 17. Settling Time (Falling)

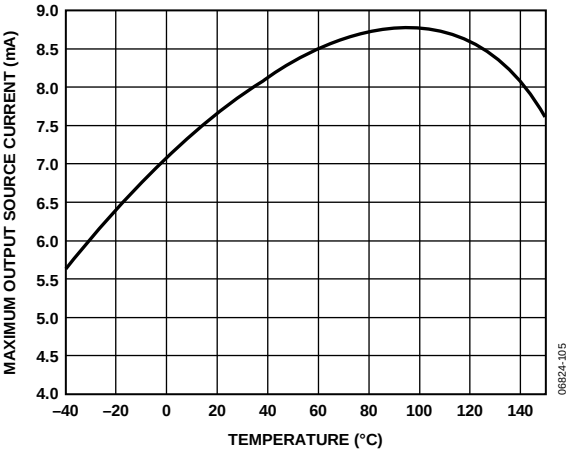


Figure 20. Maximum Output Source Current vs. Temperature

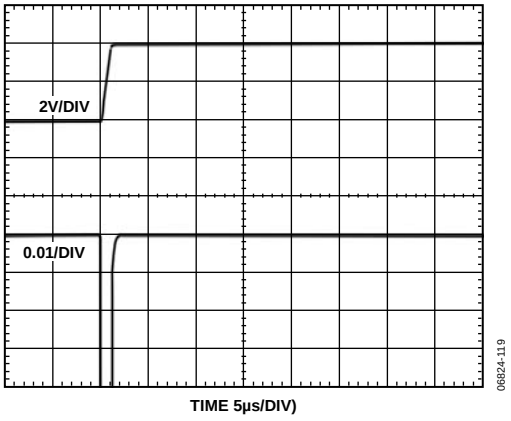


Figure 18. Settling Time (Rising)

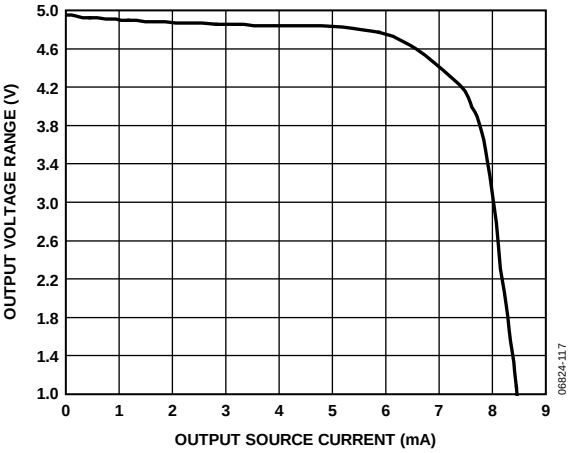


Figure 21. Output Voltage Range vs. Output Source Current

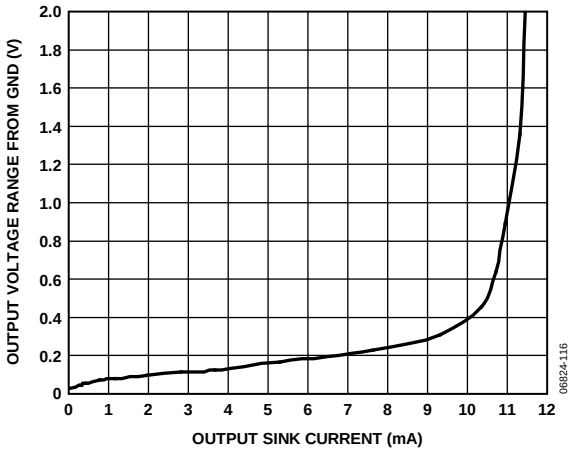


Figure 22. Output Voltage Range from GND vs. Output Sink Current

THEORY OF OPERATION

In typical applications, the AD8211 amplifies a small differential input voltage generated by the load current flowing through a shunt resistor. The AD8211 rejects high common-mode voltages (up to 65 V) and provides a ground referenced, buffered output that interfaces with an analog-to-digital converter (ADC). Figure 23 shows a simplified schematic of the AD8211.

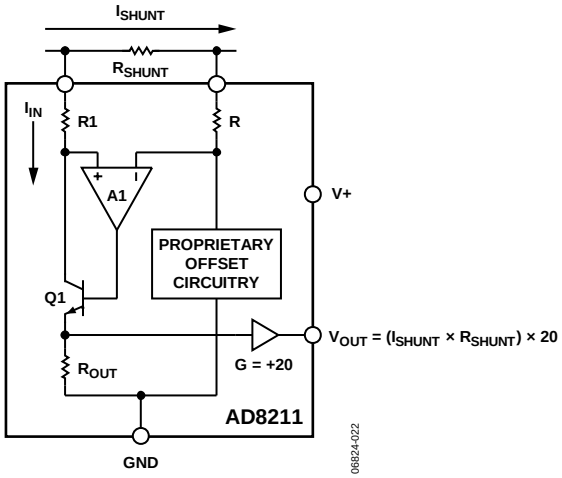


Figure 23. Simplified Schematic

A load current flowing through the external shunt resistor produces a voltage at the input terminals of the AD8211. The input terminals connect to Amplifier A1 by Resistor R and Resistor R1. The inverting terminal, which has very high input impedance, is held to the following because negligible current flows through Resistor R:

$$(V_{CM}) - (I_{SHUNT} \times R_{SHUNT})$$

Amplifier A1 forces the noninverting input to the same potential. Therefore, the current that flows through Resistor R1 is equal to

$$I_{IN} = (I_{SHUNT} \times R_{SHUNT})/R1$$

This current (I_{IN}) is converted back to a voltage via R_{OUT}. The output buffer amplifier has a gain of 20 V/V and offers excellent accuracy because the internal gain setting resistors are precision trimmed to within 0.01% matching. The resulting output voltage is equal to

$$V_{OUT} = (I_{SHUNT} \times R_{SHUNT}) \times 20$$

APPLICATION NOTES

OUTPUT LINEARITY

In all current sensing applications, and especially in automotive and industrial environments where the common-mode voltage can vary significantly, it is important that the current sensor maintain the specified output linearity, regardless of the input differential or common-mode voltage. The AD8211 contains specific circuitry on the input stage, which ensures that even when the differential input voltage is very small, and the common-mode voltage is also low (below the 5 V supply), the input-to-output linearity is maintained. Figure 24 shows the input differential voltage vs. the corresponding output voltage at different common modes.

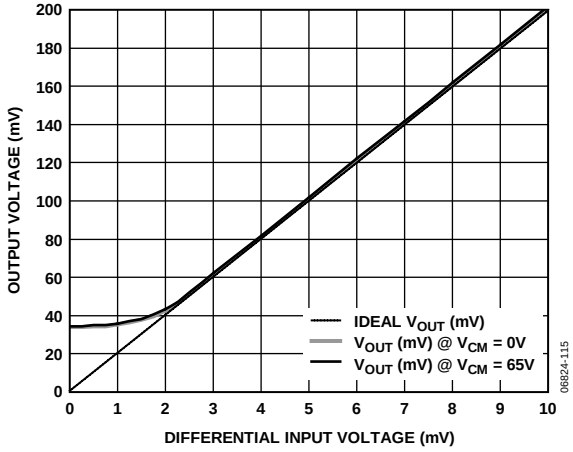


Figure 24. Gain Linearity Due to Differential and Common-Mode Voltage

Regardless of the common mode voltage, the AD8211 provides a correct output voltage when the input differential is at least 2 mV, which is due to the voltage range of the output amplifier that can go as low as 33 mV typical. The specified minimum output amplifier voltage is 100 mV to provide sufficient guard bands. The ability of the AD8211 to work with very small differential inputs, regardless of the common-mode voltage, allows for additional dynamic range, accuracy, and flexibility in any current sensing application.

APPLICATIONS INFORMATION

HIGH-SIDE CURRENT SENSE WITH A LOW-SIDE SWITCH

In such load control configurations, the PWM-controlled switch is ground referenced. An inductive load (solenoid) is tied to a power supply. A resistive shunt is placed between the switch and the load (see Figure 25). An advantage of placing the shunt on the high side is that the entire current, including the recirculation current, can be measured because the shunt remains in the loop when the switch is off. In addition, diagnostics can be enhanced because shorts to ground can be detected with the shunt on the high side. In this circuit configuration, when the switch is closed, the common-mode voltage moves down to near the negative rail. When the switch is opened, the voltage reversal across the inductive load causes the common-mode voltage to be held one diode drop above the battery by the clamp diode.

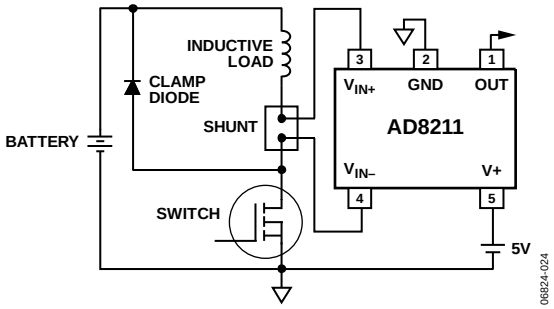


Figure 25. Low-Side Switch

HIGH-SIDE CURRENT SENSING

In this configuration, the shunt resistor is referenced to the battery. High voltage is present at the inputs of the current sense amplifier. In this mode, the recirculation current is again measured and shorts to ground can be detected. When the shunt is battery referenced, the AD8211 produces a linear ground referenced, analog output. An AD8214 can also provide an overcurrent detection signal in as little as 100 ns. This feature is useful in high current systems where fast shutdown in overcurrent conditions is essential.

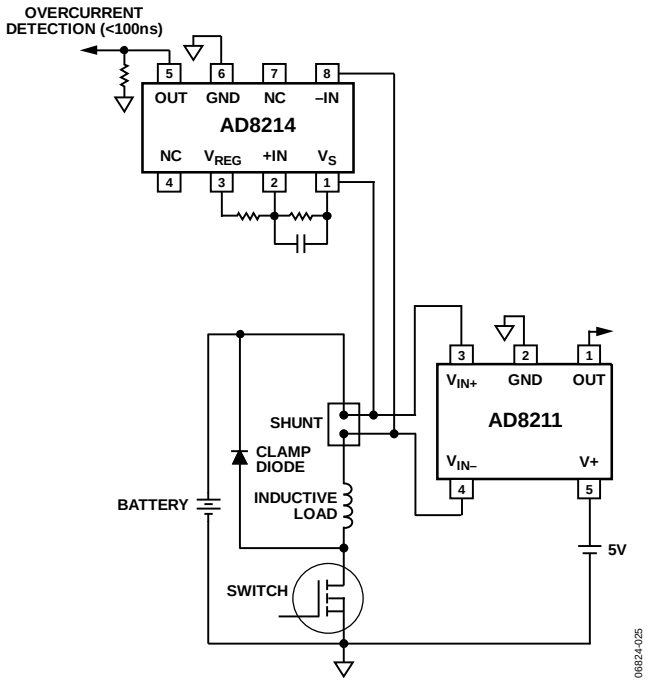


Figure 26. Battery Referenced Shunt Resistor

LOW-SIDE CURRENT SENSING

In systems where low-side current sensing is preferred, the AD8211 provides an integrated solution with great accuracy. Ground noise is rejected, CMRR is typically higher than 90 dB, and output linearity is not compromised, regardless of the input differential voltage.

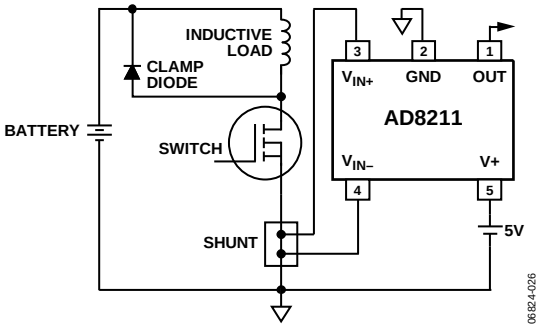
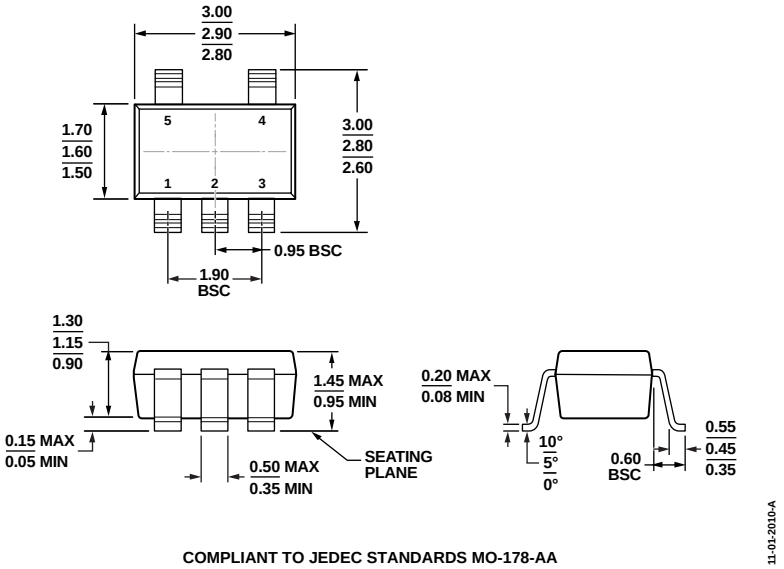


Figure 27. Ground Referenced Shunt Resistor

OUTLINE DIMENSIONS



COMPLIANT TO JEDEC STANDARDS MO-178-AA

Figure 28. 5-Lead Small Outline Transistor Package [SOT-23]
(RJ-5)
Dimensions shown in millimeters

ORDERING GUIDE

Model[1, 2]	Temperature Range	Package Description	Package Option	Branding
AD8211YRJZ-R2	−40°C to +125°C	5-Lead Small Outline Transistor Package [SOT-23]	RJ-5	Y02
AD8211YRJZ-RL	−40°C to +125°C	5-Lead Small Outline Transistor Package [SOT-23]	RJ-5	Y02
AD8211YRJZ-RL7	−40°C to +125°C	5-Lead Small Outline Transistor Package [SOT-23]	RJ-5	Y02
AD8211WYRJZ-R7	−40°C to +125°C	5-Lead Small Outline Transistor Package [SOT-23]	RJ-5	Y3N
AD8211WYRJZ-RL	−40°C to +125°C	5-Lead Small Outline Transistor Package [SOT-23]	RJ-5	Y3N

[1] Z = RoHS Compliant Part.
[2] W = Qualified for Automotive Applications.

AUTOMOTIVE PRODUCTS

The AD8211WYRJZ models are available with controlled manufacturing to support the quality and reliability requirements of automotive applications. Note that these automotive models may have specifications that differ from the commercial models; therefore, designers should review the Specifications section of this data sheet carefully. Only the automotive grade products shown are available for use in automotive applications. Contact your local Analog Devices account representative for specific product ordering information and to obtain the specific Automotive Reliability reports for these models.

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